



東芝

INTEGRATED CIRCUIT

TECHNICAL DATA

TA7322P

TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT

SILICON MONOLITHIC

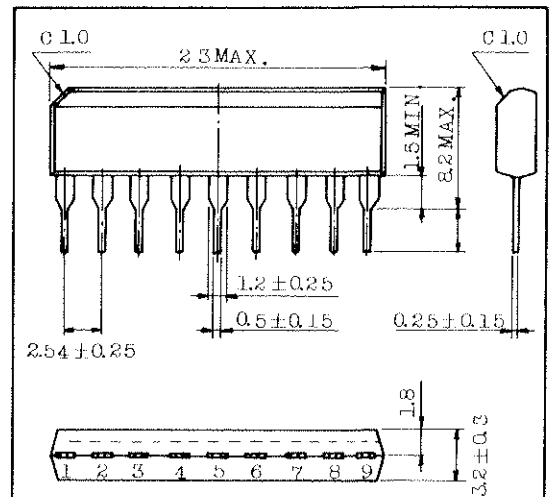
HIGH VOLTAGE, SUPER LOW NOISE PRE-AMPLIFIER WITH DUAL POWER SUPPLY.

The TA7322 is suitable for pre-amplifier of stereo or deck with equalizer, flat, tone and buffer amplifiers.

- High Voltage and High Dynamic Range.
- Low Harmonic Distortion.
- Low Impedance Drive.
- Super Low Noise. (S/N=82dB, THF-A Filter).
- High Stability for Buffer Amplifier.
- Dual Power Operation.
- Wide Operating Supply Voltage Range :

$$V_{CC}-V_{EE}=\pm 5V \sim \pm 30V.$$

Unit in mm



Lead pitch is 2.54 and tolerance is ± 0.25 against theoretical center of each lead that is obtained on the basis of No.1 lead.

JEDEC

TOSHIBA

5-23B

MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	V_{9-5}	± 30	V
Output Current	I_7	25	mAp-p
Power Dissipation (Note)	P_D	750	mW
Operating Temperature	T_{opr}	$-25 \sim 75$	$^{\circ}\text{C}$
Storage Temperature	T_{stg}	$-55 \sim 150$	$^{\circ}\text{C}$

Note : Derated above $T_a=25^{\circ}\text{C}$ in the proportion of $6\text{mW}/^{\circ}\text{C}$.

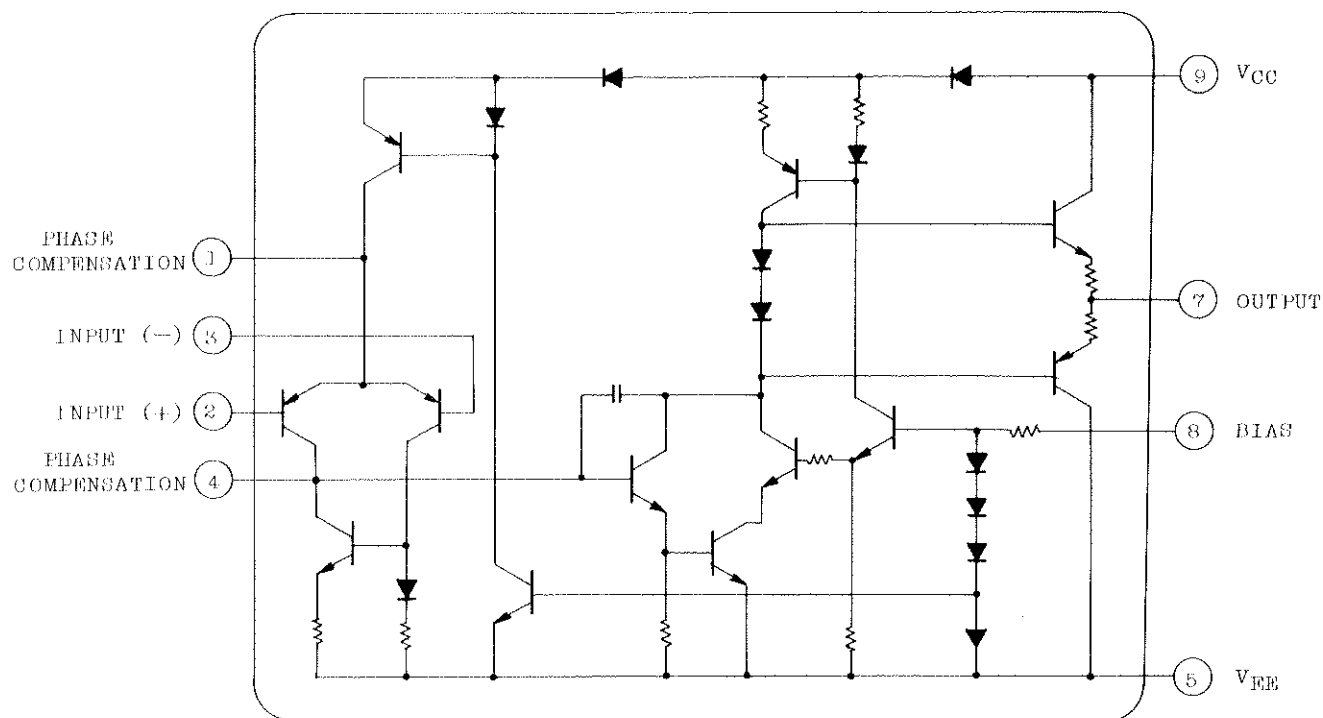
ELECTRICAL CHARACTERISTICS

($T_a=25^{\circ}\text{C}$, $V_{CC}=25\text{V}$, $V_{EE}=-25\text{V}$, RIAA EQ $f=1\text{kHz}$, $R_L=47\text{k}\Omega$)

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Quiescent Current	I_{CCQ}	1	$V_{IN}=0$	-	3.5	6.0	mA
Open Loop Voltage Gain	G_{VO}	1	$V_{IN}=-90\text{dBs}$	-	100	-	dB
Maximum Output Voltage	V_{OM}	2	$\text{THD}=0.01\%$	12	15	-	V_{rms}
Total Harmonic Distortion	$\text{THD}(1)$	2	$V_{OUT}=12V_{rms}$	-	0.002	0.01	%
	$\text{THD}(2)$	2	$f=20\text{Hz} \sim 20\text{kHz}$ $V_{OUT}=3V_{rms}$	-	0.004	-	%
Equivalent Input Noise Voltage	V_{NI}	2	$R_g=2.2\text{k}\Omega$ $\text{BW}=15\text{Hz} \sim 30\text{kHz}$	-	0.7	1.5	μV_{rms}
Signal-Noise Ratio	S/N	2	$R_g=0$, THF A Curve Filter	-	82	-	dB



EQUIVALENT CIRCUIT

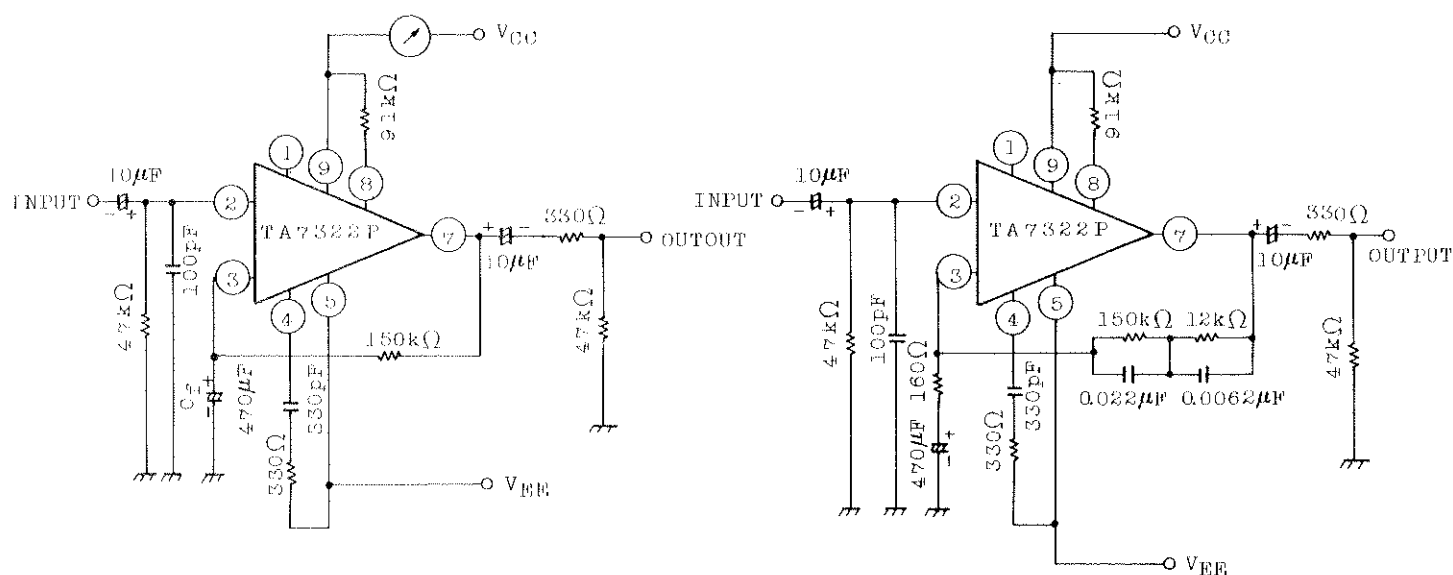


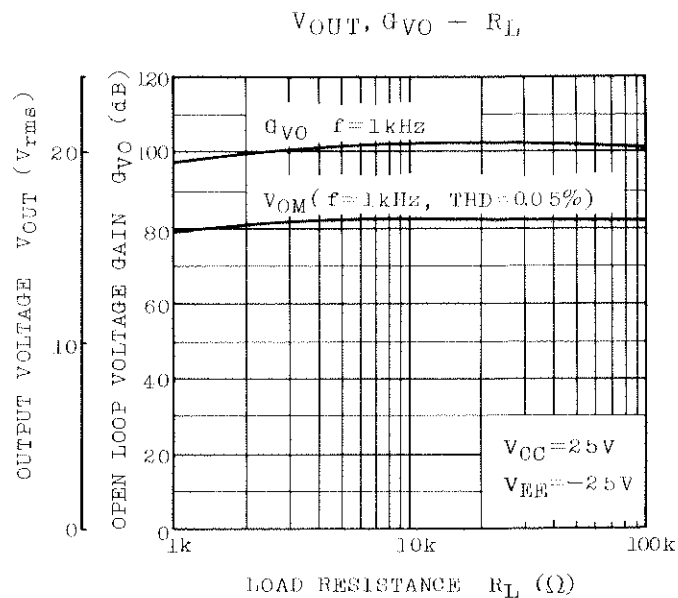
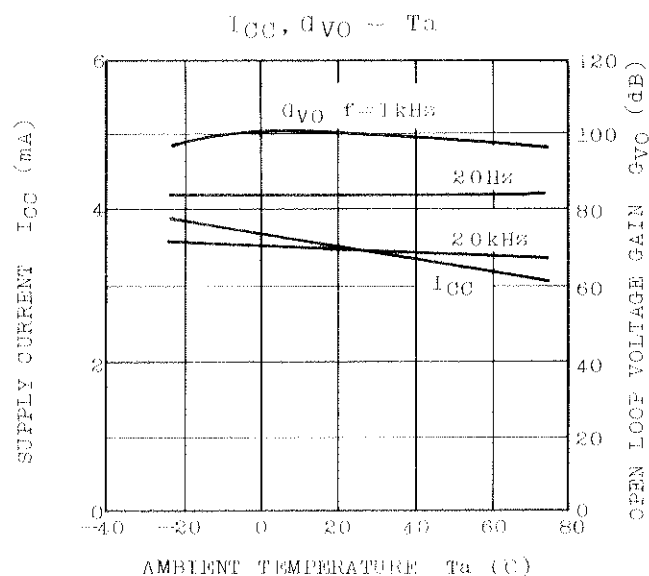
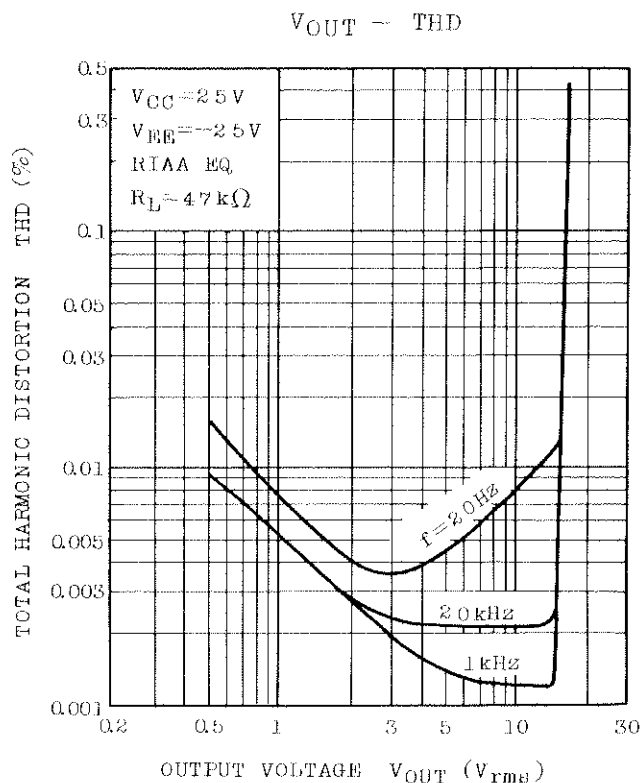
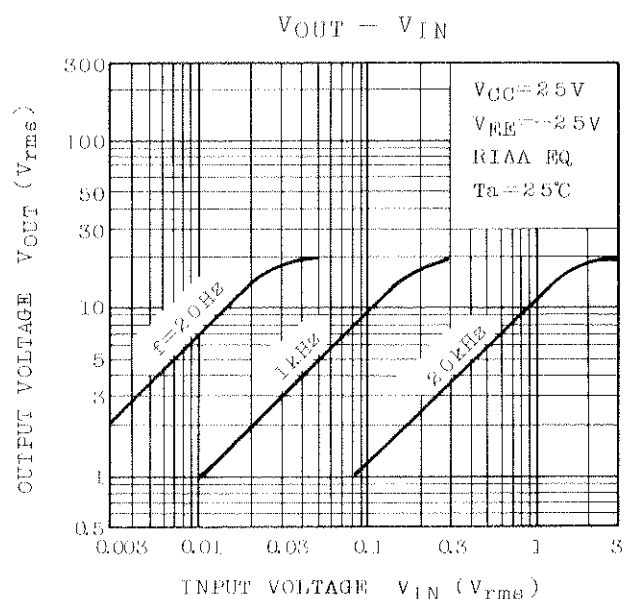
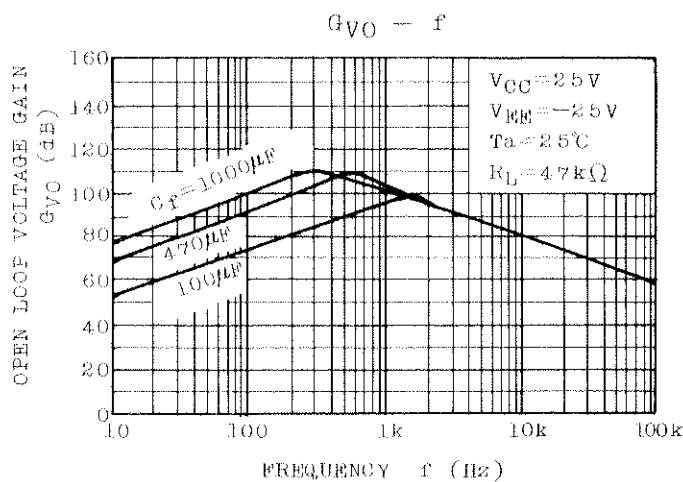
PIN 6 : NO CONNECTION

TEST CIRCUIT

1. I_{CCQ} , GVO

2. V_{OM} , THD(1), THD(2), V_{NI} , S/N







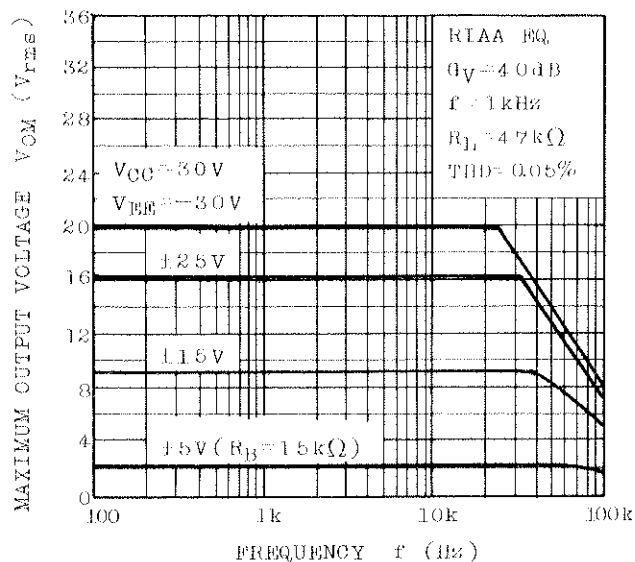
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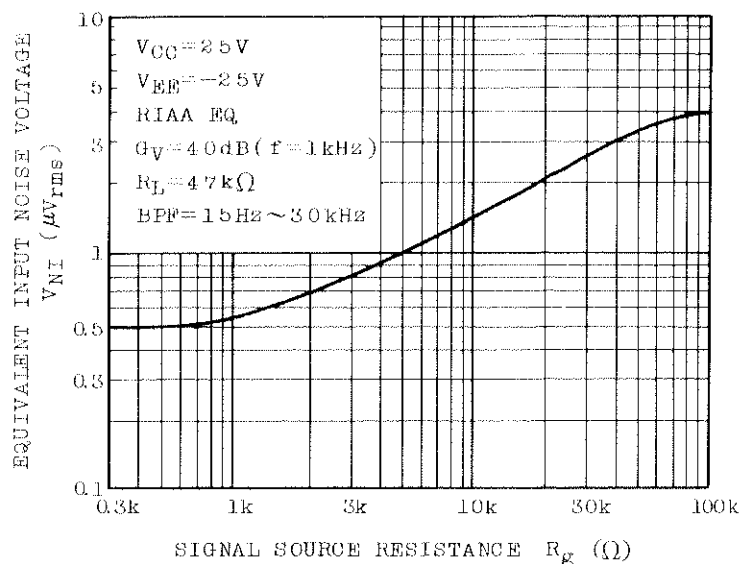
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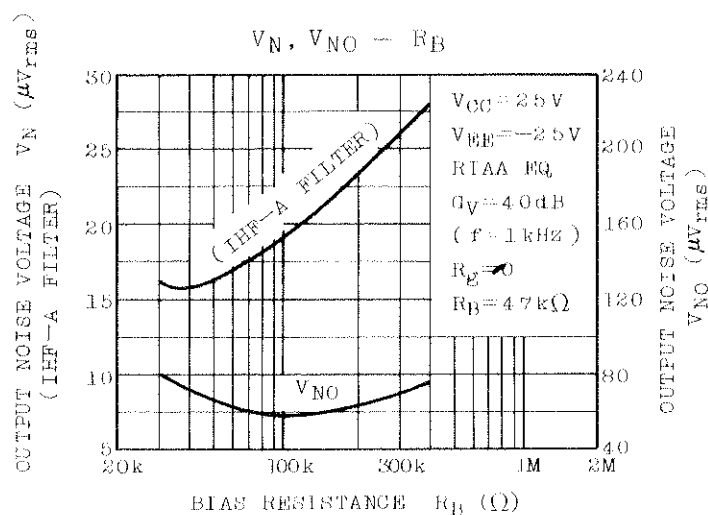
$V_{OM} - f$



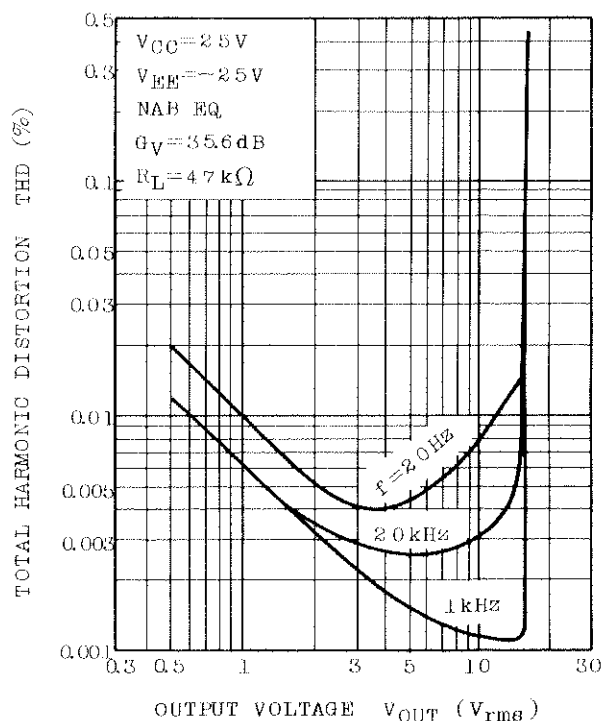
$V_{NI} - R_g$



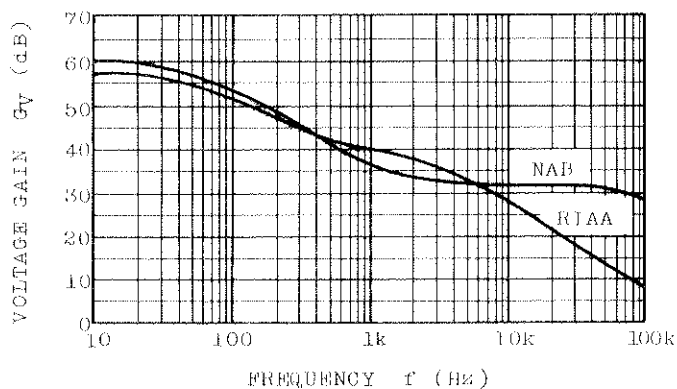
$V_N, V_{NO} - R_B$



$V_{OUT} - THD$

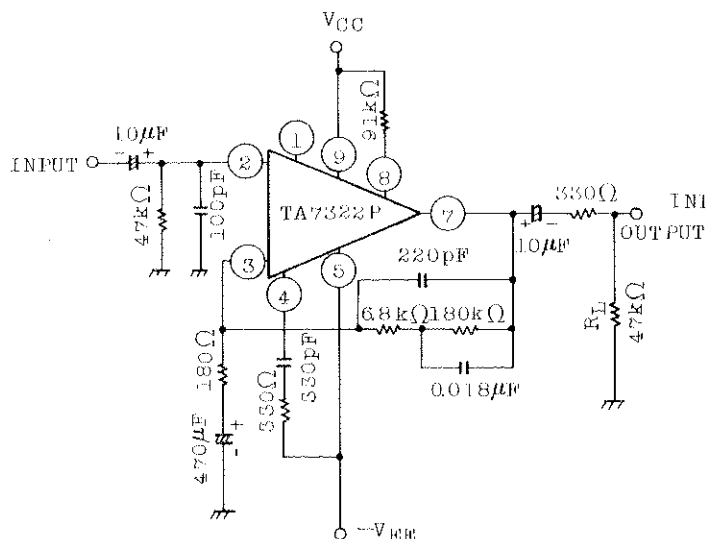


$G_V - f$

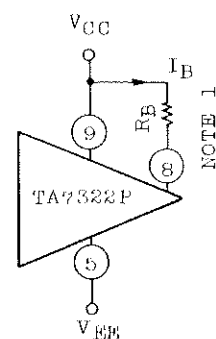
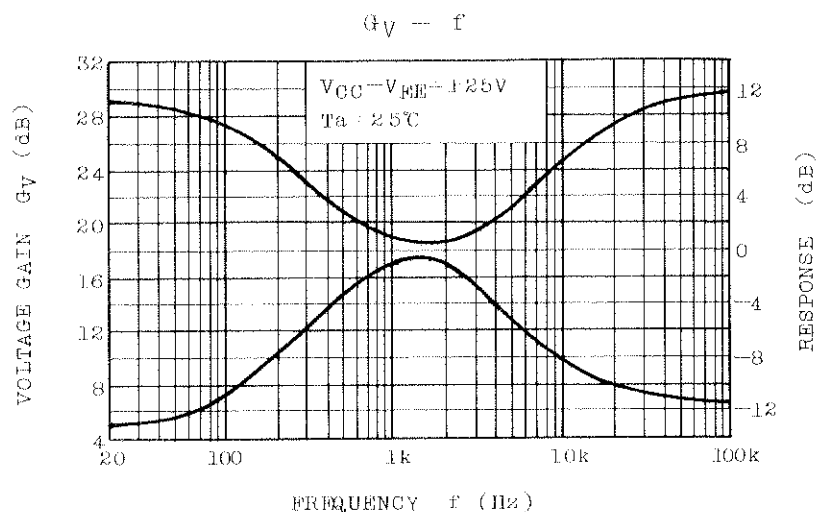
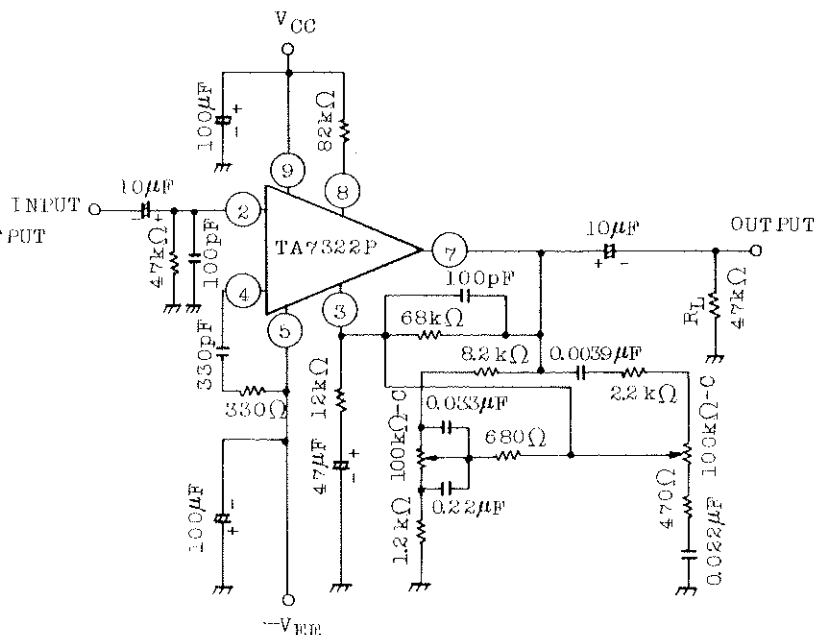


APPLICATION CIRCUIT

1. NAB EQ



2. TONE CONTROL CIRCUIT



Note 1. Institution of Bias Resistance (R_B)
In regard to the value of supply voltage, R_B is found using the following formula:

$$R_B = \frac{V_{CC} - (V_{EE}) - 5.3V}{I_B} \quad (\Omega)$$

where $I_B = 500\mu A$

(Example)

at $V_{CC} = 25V$, $V_{EE} = -25V$

$$R_B = \frac{25 + 25 - 5.3}{0.5mA} = 89.4k\Omega$$

